

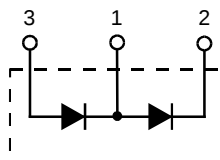
Diode Modules

$$I_{FRMS} = 2 \times 100 \text{ A}$$

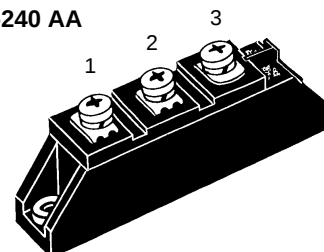
$$I_{FAVM} = 2 \times 64 \text{ A}$$

$$V_{RRM} = 800-1800 \text{ V}$$

V_{RSM} V	V_{RRM} V	Type
900	800	MDD 44-08N1 B
1300	1200	MDD 44-12N1 B
1500	1400	MDD 44-14N1 B
1700	1600	MDD 44-16N1 B
1900	1800	MDD 44-18N1 B



TO-240 AA



Symbol	Test Conditions	Maximum Ratings
I_{FRMS}	$T_{VJ} = T_{VJM}$	100 A
I_{FAVM}	$T_C = 92^\circ\text{C}; 180^\circ \text{ sine}$	64 A
	$T_C = 100^\circ\text{C}; 180^\circ \text{ sine}$	59 A
I_{FSM}	$T_{VJ} = 45^\circ\text{C}; V_R = 0$	t = 10 ms (50 Hz), sine 1150 A
		t = 8.3 ms (60 Hz), sine 1300 A
	$T_{VJ} = T_{VJM}; V_R = 0$	t = 10 ms (50 Hz), sine 1000 A
		t = 8.3 ms (60 Hz), sine 1200 A
$\int i^2 dt$	$T_{VJ} = 45^\circ\text{C}; V_R = 0$	t = 10 ms (50 Hz), sine 6600 A ² s
		t = 8.3 ms (60 Hz), sine 7000 A ² s
	$T_{VJ} = T_{VJM}; V_R = 0$	t = 10 ms (50 Hz), sine 5000 A ² s
		t = 8.3 ms (60 Hz), sine 5950 A ² s
T_{VJ}		-40...+150 °C
T_{VJM}		150 °C
T_{stg}		-40...+125 °C
V_{ISOL}	50/60 Hz, RMS t = 1 min	3000 V~
	$I_{ISOL} \leq 1 \text{ mA}$ t = 1 s	3600 V~
M_d	Mounting torque (M5)	2.5-4/22-35 Nm/lb.in.
	Terminal connection torque (M5)	2.5-4/22-35 Nm/lb.in.
Weight	Typical including screws	90 g

Features

- International standard package JEDEC TO-240 AA
- Direct copper bonded Al_2O_3 -ceramic base plate
- Planar passivated chips
- Isolation voltage 3600 V~
- UL registered, E 72873

Applications

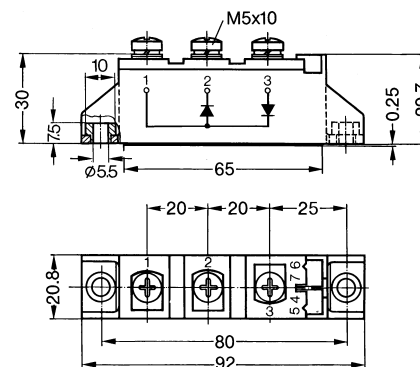
- Supplies for DC power equipment
- DC supply for PWM inverter
- Field supply for DC motors
- Battery DC power supplies

Advantages

- Space and weight savings
- Simple mounting
- Improved temperature and power cycling
- Reduced protection circuits

Symbol	Test Conditions	Characteristic Values
I_R	$T_{VJ} = T_{VJM}; V_R = V_{RRM}$	10 mA
V_F	$I_F = 200 \text{ A}; T_{VJ} = 25^\circ\text{C}$	1.60 V
V_{T0}	For power-loss calculations only	0.8 V
r_T	$T_{VJ} = T_{VJM}$	4.3 mΩ
Q_S	$T_{VJ} = 125^\circ\text{C}; I_F = 50 \text{ A}, -di/dt = 0.64 \text{ A}/\mu\text{s}$	90 μC
I_{RM}		11 A
R_{thJC}	per diode; DC current	0.59 K/W
	per module	0.295 K/W
R_{thJK}	per diode; DC current	0.79 K/W
	per module	0.395 K/W
d_s	Creepage distance on surface	12.7 mm
d_A	Strike distance through air	9.6 mm
a	Maximum allowable acceleration	50 m/s ²

Dimensions in mm (1 mm = 0.0394")



Data according to IEC 60747 and refer to a single diode unless otherwise stated.
IXYS reserves the right to change limits, test conditions and dimensions

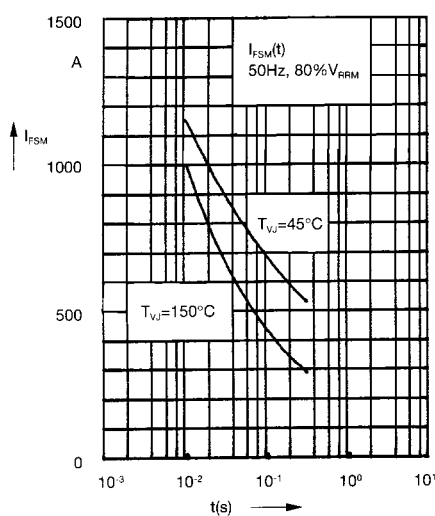


Fig. 1 Surge overload current
 I_{FSM} : Crest value, t : duration

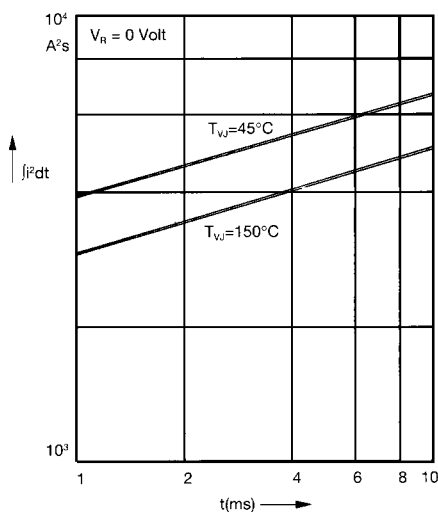


Fig. 2 $\int i^2 dt$ versus time (1-10 ms)

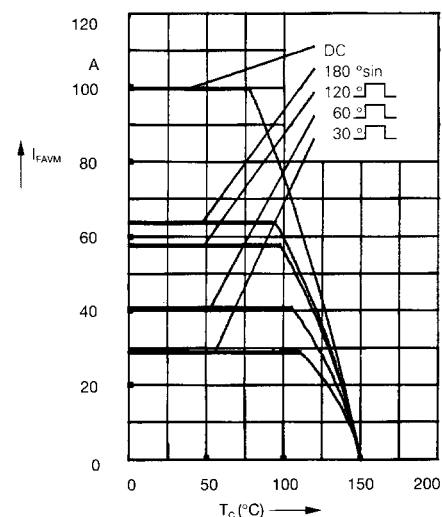


Fig. 2a Maximum forward current at case temperature

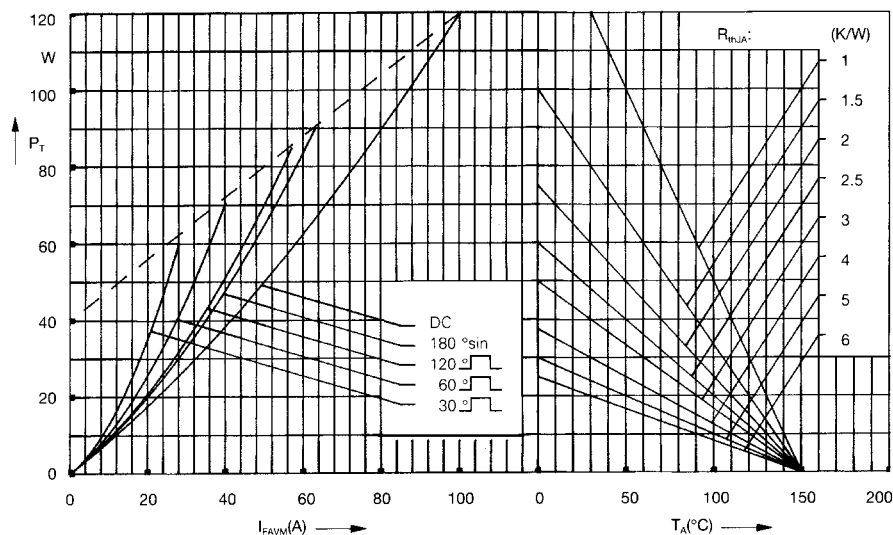


Fig. 3 Power dissipation versus forward current and ambient temperature (per diode)

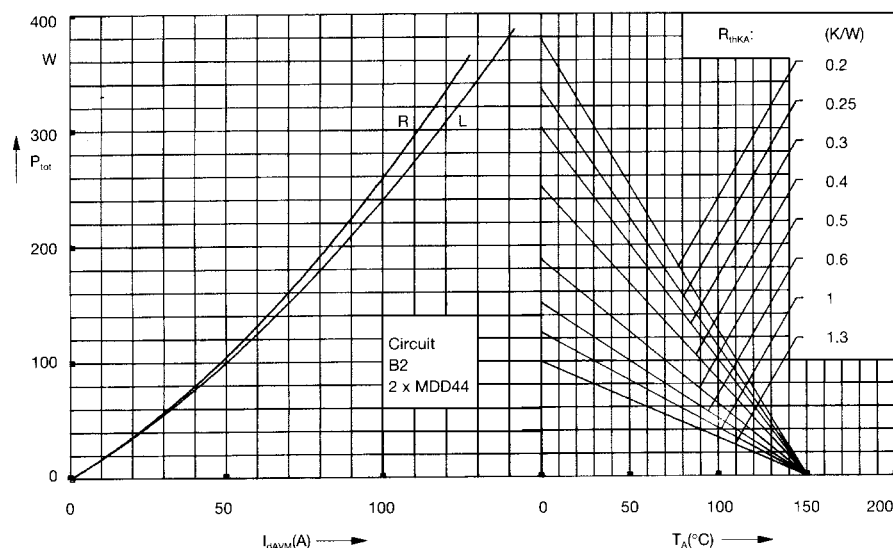


Fig. 4 Single phase rectifier bridge:
Power dissipation versus direct output current and ambient temperature
R = resistive load
L = inductive load

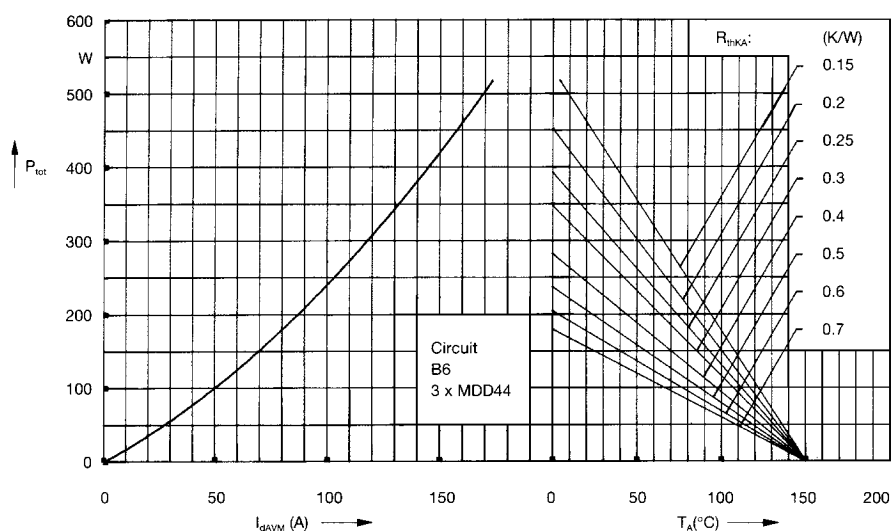


Fig. 5 Three phase rectifier bridge:
Power dissipation versus direct
output current and ambient
temperature

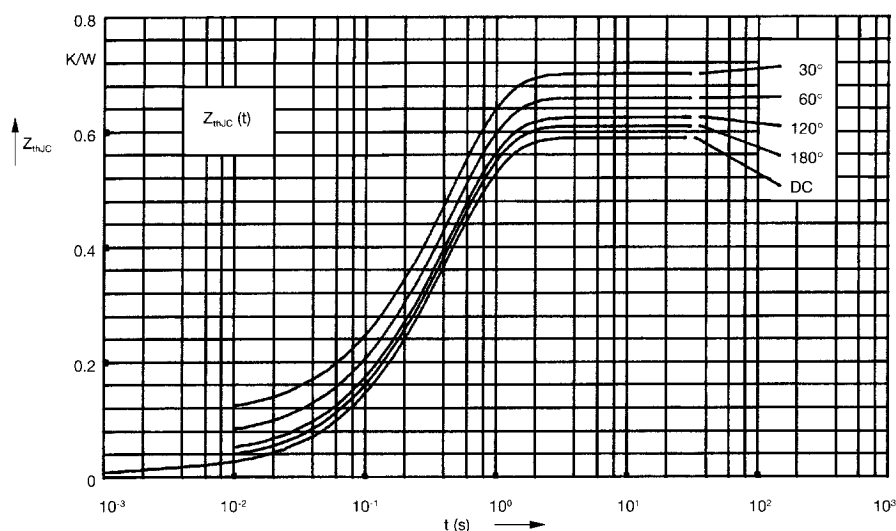


Fig. 6 Transient thermal impedance
junction to case (per diode)

R_{thJC} for various conduction angles d:

d	R_{thJC} (K/W)
DC	0.59
180°	0.61
120°	0.63
60°	0.66
30°	0.70

Constants for Z_{thJC} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.012	0.0012
2	0.045	0.095
3	0.533	0.455

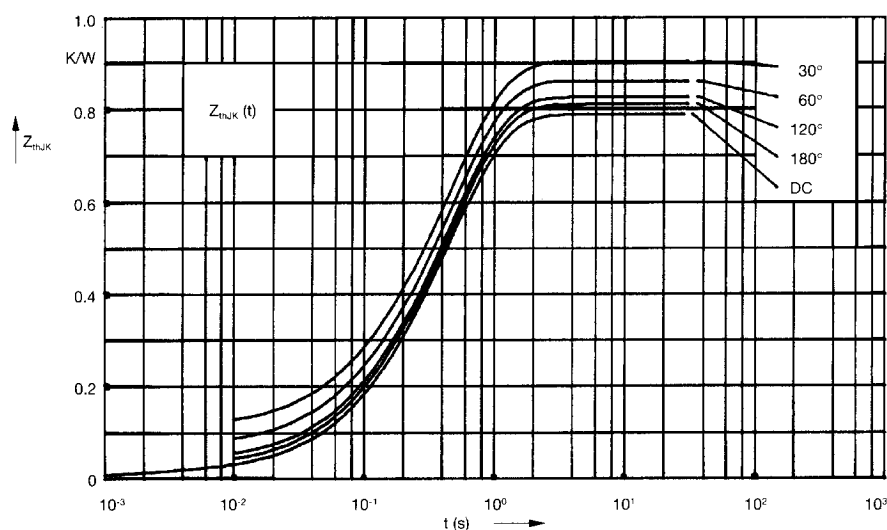


Fig. 7 Transient thermal impedance
junction to heatsink (per diode)

R_{thJK} for various conduction angles d:

d	R_{thJK} (K/W)
DC	0.79
180°	0.81
120°	0.83
60°	0.86
30°	0.90

Constants for Z_{thJK} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.012	0.0012
2	0.045	0.095
3	0.533	0.455
4	0.2	0.495

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